NSN 5961-01-076-3973

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Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-076-3973 **Inclosure Material:** Glass **Overall Length:** Between 0.195 inches and 0.300 inches **Terminal Length:** Between 1.000 inches and 1.500 inches **Overall Diameter:** Between 0.078 inches and 0.107 inches **Mounting Method:** Terminal **Features Provided:** Hermetically sealed case **Criticality Code Justification:** Feat **Semiconductor Material:** Silicon **Voltage Rating In Volts Per Characteristic:** 100.0 reverse breakdown voltage, dc and 75.0 working peak reverse voltage **Current Rating Per Characteristic:** 75.00 milliamperes forward current, average absolute and 500.00 milliamperes forward current, average preset **Maximum Operating Tempurature Per Measurement Point:** 175.0 degrees celsius ambient air **Special Features:** Item must comply with requirements of defense electronic supply center production standard no. L02740; for navy nuclear propulsion plant products only; junction pattern arrangement: pn **Terminal Type And Quantity:** 2 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: